NSN 5961-00-350-7767

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Inclosure Material:

Metal

Overall Length:

Between 1.440 inches and 1.525 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case and mounting hardware

Overall Width Across Flats:

Between 0.865 inches and 0.875 inches

Thread Size:

0.312 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

40.0 collector to emitter voltage, dc and 60.0 collector to base voltage, dc and 8.0 emitter to base voltage, dc

Current Rating Per Characteristic:

20.00 amperes source cutoff current and 5.00 amperes source cutoff current

Power Rating Per Characteristic:

100.0 watts small-signal input power, common-collector preset

Transfer Ratio:

15.0 static forward current transfer ratio, common-emitter

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Thread Series Designator:

Unf

Terminal Type And Quantity:

2 tab, solder lug and 1 wire hook

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

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